

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3941	250/370\$	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:35
L4	31	250/370.09 and sensor and matrix and photosensor and (intrinsic adj storage or storage)	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:41
L5	272	250/370.07\$	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:41
L6	31	250/370.09 and sensor adj matrix	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:42
L7	5	250/370.07 and sensor adj matrix	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:42
L8	1	250/370.07 and sensor adj matrix and storage adj capacitance	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:42
L9	2	250/370.07 and sensor adj matrix and storage and transistor and (switch or switch adj line or switching adj line)	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:42
L10	11	250/370.09 and sensor adj matrix and storage and transistor and (switch or switch adj line or switching adj line)	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:43
L15	18	250/370.09 and (sensor adj matrix or sensor adj series) and transistor and (switch or switch adj line or switching adj line)	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:44
L16	42	"x-ray" and (sensor adj matrix or sensor adj series) and transistor and (switch or switch adj line or switching adj line)	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:45
L17	17	"x-ray" and photosensor and (sensor adj matrix or sensor adj series) and transistor and (switch or switch adj line or switching adj line)	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:45
L18	3	"x-ray" and photosensor and (sensor adj matrix or sensor adj series) and transistor and (switch or switch adj line or switching adj line) and control adj line	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:46

L19	3	"x-ray" and photosensor and (sensor adj matrix or sensor adj series) and transistor and (switch or switch adj line or switching adj line) and control adj line and substrate	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:46
L20	3	photosensor and (sensor adj matrix or sensor adj series) and transistor and (switch or switch adj line or switching adj line) and control adj line and substrate	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:46
L21	10	photosensor and (sensor adj matrix or sensor adj series) and (storage adj capacitance or storage adj capacitor)	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:47
L22	2	photosensor and (sensor adj matrix or sensor adj series) and (storage adj capacitance or storage adj capacitor) and switch\$4 adj line	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:47
S28	1421	250/370.09	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:35
S30	5	250/370.09 and sensor and matrix and photosensor adj element	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:41
S32	24	250/370.09 and sensor and matrix and photosensor and (intrinsic adj storage or storage) and transistor and (switching adj line or switching or switch adj line or switch)	US-PGPUB; USPAT; EPO; DERWENT	OR	ON	2004/12/17 16:35